## NSN 5962-01-351-9523



Memory Microcircuit - Page 1 of 2
View Online at https://aerobasegroup.com/nsn/5962-01-351-9523
Overall Height:
0.400 inches
Body Length:
1.280 inches
Body Width:
Between 0.220 inches and 0.310 inches
Body Height:
Between 0.140 inches and 0.185 inches
Maximum Power Dissipation Rating:
1.02 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Satellite communications terminal an/usc-3 (v) 1
Features Provided:
Hermetically sealed and burn in and monolithic and programmed
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
14 input
Case Outline Source And Designator:
D-9 mil-m-38510
Current Rating Per Characteristic:
185.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts, nower source and 7.0 volts, nower source

#### **Capitance Rating Per Characteristic:**

8.00 input picofarads and 15.00 output picofarads

#### **Time Rating Per Chacteristic:**

25.00 nanoseconds delay

#### **Memory Device Type:**

Prom

### **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

# NSN 5962-01-351-9523

Memory Microcircuit - Page 2 of 2



	Ī	erminal	Type	And	Quantit	y:
--	---	---------	------	-----	---------	----

24 printed circuit

Shelf Life:

N/a

**Unit Of Measure:** 

--

Demilitarization:

Yes - demil/mli

Fiig:

A458a0